onsemi

NPN General-Purpose Amplifier

2N5551

Description

This device is designed for general-purpose high-voltage amplifiers and gas discharge display drivers.

Features

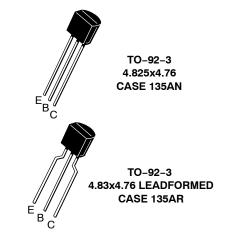
• These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant

ABSOLUTE MAXIMUM RATINGS (Note 1)

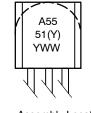
Symbol	Parameter	Value	Unit
V _{CEO}	Collector-Emitter Voltage	160	V
V _{CBO}	Collector-Base Voltage	180	V
V _{EBO}	Emitter-Base Voltage	6	V
۱ _C	Collector Current – Continuous	600	mA
T _J , T _{STG}	Operating and Storage Temperature (Note 2)	–55 to + 150	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

- These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.
- These ratings are based on a maximum junction temperature of 150°C. These are steady-state limits. onsemi should be consulted on applications involving pulsed or low-duty cycle operations.



MARKING DIAGRAM



A = Assembly Location 5551(Y) = Specific Device Code Y = Year WW = Work Week

ORDERING INFORMATION

See detailed ordering and shipping information on page 5 of this data sheet.

THERMAL CHARACTERISTICS ($T_A = 25^{\circ}C$ unless otherwise noted) (Note 3)

Symbol	Characteristic	Мах	Unit
PD	Total Device Dissipation	625	mW
	Derate Above 25°C	5.0	mW/°C
$R_{ hetaJC}$	Thermal Resistance, Junction to Case	83.3	°C/W
$R_{ hetaJA}$	Thermal Resistance, Junction to Ambient	200	°C/W

ELECTRICAL CHARACTERISTICS ($T_A = 25^{\circ}C$ unless otherwise noted) (Note 4)

Symbol	Parameter	Test Conditions	Min	Max	Unit
V _{(BR)CEO}	Collector-Emitter Breakdown Voltage	$I_{\rm C} = 1.0 \text{ mA}, I_{\rm B} = 0$	160		V
V _{(BR)CBO}	Collector-Base Breakdown Voltage	$I_{C} = 100 \ \mu A, \ I_{E} = 0$	180		V
V _{(BR)EBO}	Emitter-Base Breakdown Voltage	I _E = 10 μA, I _C = 0	6.0		V
I _{CBO}	Collector Cut-Off Current	$V_{CB} = 120 \text{ V}, \text{ I}_{E} = 0$		50	nA
		V_{CB} = 120 V, I _E = 0 V, T _A = 100°C		50	μΑ
I _{EBO}	Emitter Cut-Off Current	$V_{EB} = 4.0 \text{ V}, \text{ I}_{C} = 0$		50	nA

ON CHARACTERISTICS

h _{FE}	DC Current Gain	I _C = 1.0 mA, V _{CE} = 5.0 V	80		
		I _C = 10 mA, V _{CE} = 5.0 V	80	250	
		I _C = 10 mA, V _{CE} = 5.0 V (for 2N5551YBU, 2N5551YTA)	180	240	
		I _C = 50 mA, V _{CE} = 5.0 V	30		
V _{CE(sat)}	Collector-Emitter Saturation Voltage	I _C = 10 mA, I _B = 1.0 mA		0.15	V
		I _C = 50 mA, I _B = 5.0 mA		0.20	V
V _{BE(sat)}	Base-Emitter On Voltage	I _C = 10 mA, I _B = 1.0 mA		1.0	V
		I _C = 50 mA, I _B = 5.0 mA		1.0	V

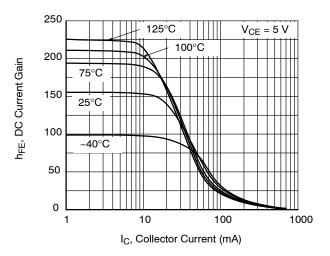
SMALL-SIGNAL CHARACTERISTICS

f _T	Current Gain Bandwidth Product	I_{C} = 10 mA, V_{CE} = 10 V, f = 100 MHz	100		MHz
C _{obo}	Output Capacitance	V_{CB} = 10 V, I _E = 0, f = 1.0 MHz		6.0	pF
C _{ibo}	Input Capacitance	V_{BE} = 0.5 V, I _C = 0, f = 1.0 MHz		20	pF
H _{fe}	Small-Signal Current Gain	$I_{\rm C}$ = 1.0 mA, $V_{\rm CE}$ = 10 V, f = 1.0 kHz	50	250	
NF	Noise Figure	I_{C} = 250 μA, V _{CE} = 5.0 V, R _S = 1.0 kΩ, f = 10 Hz to 15.7 kHz		8.0	dB

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions. 3. PCB board size $FR-4.76 \times 114 \times 0.6 T \text{ mm}^3$ (3.0 inch x 4.5 inch x 0.062 inch) with minimum land pattern size.

4. Pulse test: pulse width \leq 300 μ s, duty cycle \leq 2.0%.

TYPICAL PERFORMANCE CHARACTERISTICS





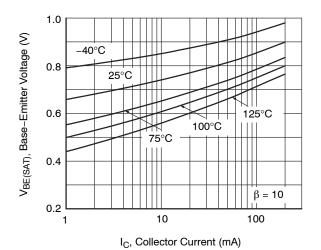
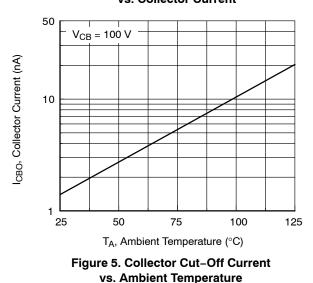


Figure 3. Base–Emitter Saturation Voltage vs. Collector Current



 $\beta = 10$ V_{CE(SAT)}, Collector Emitter Voltage (V) 10 1 125°C 100°C Ν 0.1 C 75 25°C П -40°C 0.01 10 100 1

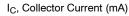


Figure 2. Collector– Emitter Saturation Voltage vs. Collector Current

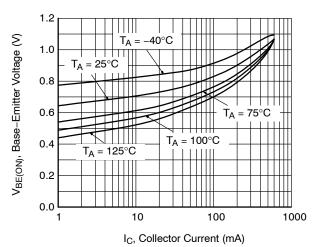
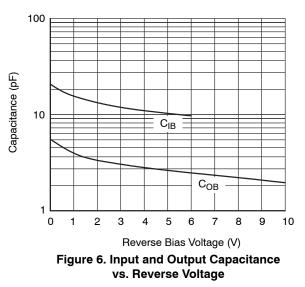


Figure 4. Base–Emitter On Voltage vs. Collector Current



TYPICAL PERFORMANCE CHARACTERISTICS (CONTINUED)

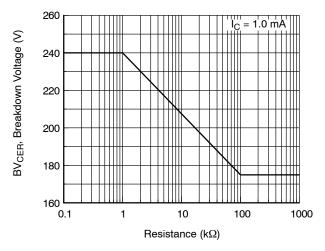


Figure 7. Collector–Emitter Breakdown Voltage with Resistance between Emitter–Base

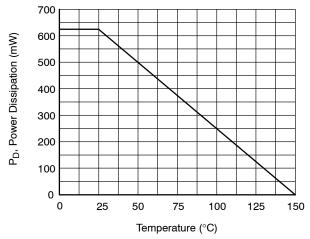


Figure 9. Power Dissipation vs. Ambient Temperature

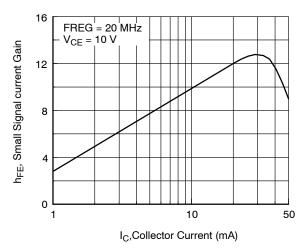


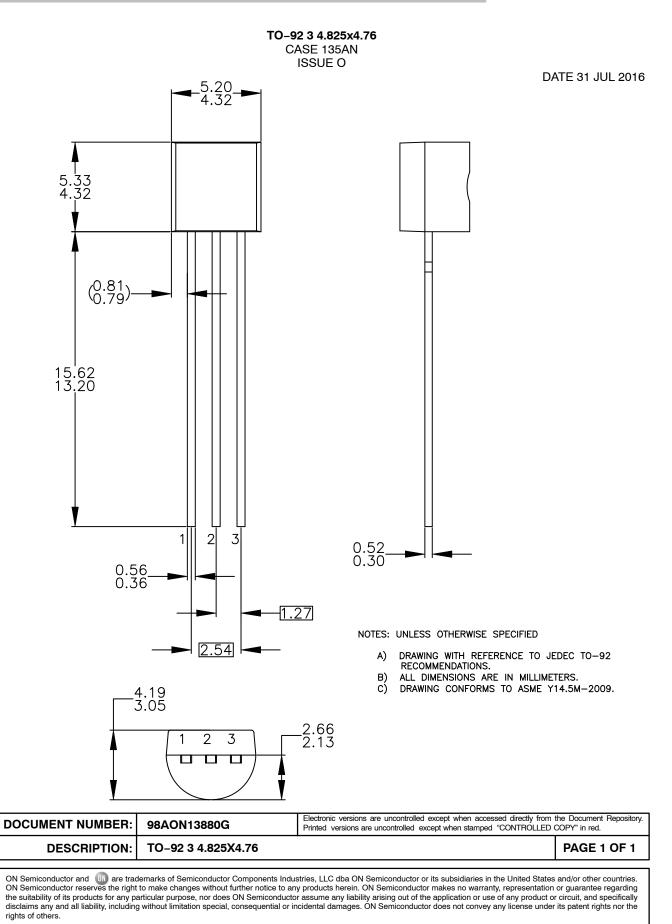
Figure 8. Small Signal Current Gain vs. Collector Current

ORDERING INFORMATION (Note 5)

Part Number	Top Mark	Package	Shipping [†]
2N5551TA	5551	TO-92-3, Case 135AR (Pb-Free)	2000 / Ammo Pack
2N5551TFR	5551	TO-92-3, Case 135AR (Pb-Free)	2000 / Tape & Reel
2N5551TF	5551	TO-92-3, Case 135AR (Pb-Free)	2000 / Tape & Reel
2N5551BU	5551	TO-92-3, Case 135AN (Pb-Free)	10000 / Bulk Bag
2N5551YBU	5551Y	TO-92-3, Case 135AN (Pb-Free)	10000 / Bulk Bag
2N5551YTA	5551Y	TO-92-3, Case 135AR (Pb-Free)	2000 / Ammo Pack

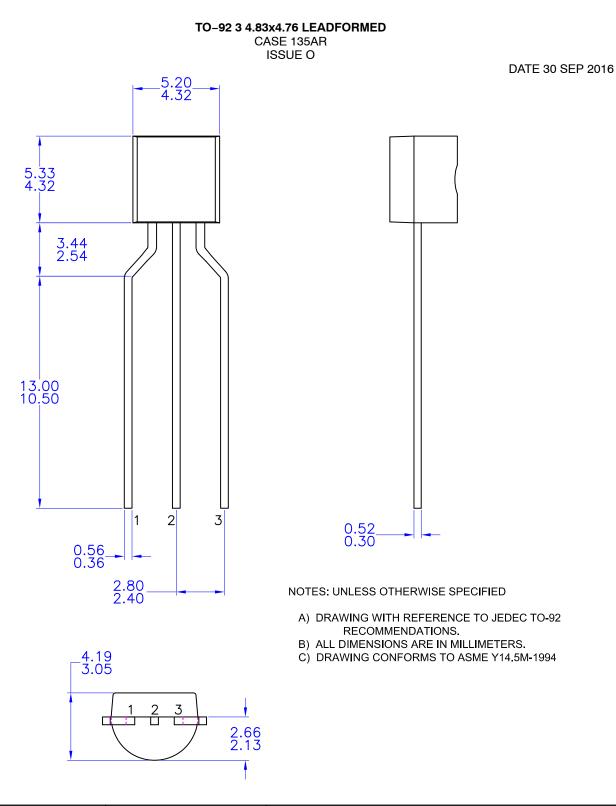
†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D. 5. Suffix "-Y" means h_{FE} 180~240 in 2N5551 (Test condition: $I_C = 10$ mA, $V_{CE} = 5.0$ V)





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